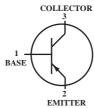


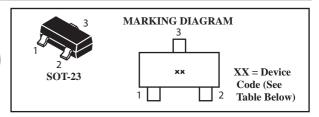
**BC856A/B-BC857A/B/C** BC858A/B/C-BC859B/C

# **General Purpose Transistor PNP Silicon**



**Pb** Lead(Pb)-Free





### Maximum Ratings (TA=25°C unless otherwise noted)

Rating		Symbol	Value	Unit
Collector-Emitter Voltage	BC856	VCEO	-65	
	BC857		-45	V
В	C858,BC859		-30	
Collector-Base Voltage	BC856		-80	
	BC857	V <sub>CBO</sub>	-50	V
В	C858,BC859		-30	
Emitter-Base VOltage		V <sub>EBO</sub>	-5.0	V
Collector Current-Continuo	us	lc	-100	mAdc

### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Total Device Dissipation FR-5 Board <sup>(1)</sup> (Note 1.)T <sub>A</sub> =25°C Derate above 25°C	PD	225 1.8	mW mW/ Ĉ
Thermal Resistance, Junction to Ambient	R <sub>θ</sub> JA	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2.) T <sub>A</sub> =25°C Derate above 25°C	PD	300 2.4	mW mW/Ĉ
Thermal Resistance, Junction to Ambient	RθJA	417	°C/W
Junction and Storage, Temperature	T <sub>J,Tstg</sub>	-55 to +150	°C

 $<sup>1.</sup>FR-5=1.0 \times 0.75 \times 0.062$  in.  $2.Alumina=0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.

#### Electrical Characteristics (TA=25°C Unless Otherwise noted)

Character	Symbol	Min	Тур	Max	Unit	
Off Characteristics						
Collector-Emitter Breakdown Voltage (IC= -10mA)	BC856 Series BC857 Series BC858, BC859 Series	V <sub>(BR)</sub> CEO	-65 -45 -30	- - -	- - -	V
Collector-Emitter Breakdown Voltage ( $I_C$ =-10 $\mu A$ , $V_{EB}$ =0)	BC856 Series BC857 Series BC858, BC859 Series	V(BR)CES	-80 -50 -30	- - -		V
Collector-Base Breakdown Voltage (I <sub>C</sub> =-10 µA)	BC856 Series BC857 Series BC858, BC859 Series	V <sub>(BR)</sub> CBO	-80 -50 -30	- - -	- - -	V
Emitter-Base Breakdown Voltage (I <sub>E</sub> =-1.0 μA)	BC856 Series BC857 Series BC858, BC859 Series	V <sub>(BR)EBO</sub>	-5.0 -5.0 -5.0	- - -	- - -	V
Collector Cutoff Current (V <sub>CB</sub> =-30V) (V <sub>CB</sub> =-30V,T <sub>A</sub> =150°	C)	I <sub>CBO</sub>	-	-	-15 -4.0	nA m <sub>A</sub>



### **Electrical Characteristics** (TA=25°C Unless Otherwise noted)

Characteristics	Symbol	Min	Тур	Max	Unit
tics					
	her				
BC856A, BC857A, BC858A	''FE	-	90	-	
BC856B, BC857B, BC858B		-	150	-	-
BC858C		-	270	-	
BC856A, BC857A, BC858A		125	180	250	
BC856B, BC857B, BC858B, BC859B		220	290	475	
BC857C, BC858C, BC859C		420	520	800	
n Voltage					V
	VCF(sat)	-	-	-0.3	
	CE(Sut)	-	-	-0.65	
ltage					V
	V <sub>BE(sat)</sub>	_	-0.7	-	
		-	-0.9	-	
					V
	V <sub>BE(on)</sub>	-0.6	-	-0.75	
	)	_	-	-0.82	
	BC856A, BC857A, BC858A BC856B, BC857B, BC858B BC858C BC856A, BC857A, BC858A BC856B, BC857B, BC858B, BC859B BC857C, BC858C, BC859C	BC856A, BC857A, BC858A BC856B, BC857B, BC858B BC858C BC856A, BC857A, BC858A BC856B, BC857B, BC858B, BC859B BC857C, BC858C, BC859C  n Voltage  VCE(sat)	BC856A, BC857A, BC858A BC856B, BC857B, BC858B BC856A, BC857A, BC858A BC856A, BC857A, BC858A BC856B, BC857B, BC858B, BC859B BC857C, BC858C, BC859C  Itage  VCE(sat)  VBE(sat)	BC856A, BC857A, BC858A BC856B, BC857B, BC858B BC856A, BC857A, BC858B BC856A, BC857A, BC858A BC856B, BC857B, BC858B, BC859B BC857C, BC858C, BC859C BC857C, BC858C	BC856A, BC857A, BC858A BC856B, BC857B, BC858B BC856C BC856A, BC857A, BC858A BC856A, BC857A, BC858A BC856B, BC857B, BC858B, BC859B BC857C, BC858C, BC859C  IVCE(sat)  VCE(sat)  VBE(sat)  VBE(on)  VBE(on)  - 0.6  - 0.75

## **Small-signal Characteristics**

Current-Gain-Bandwidth Product (I <sub>C</sub> = -10mA, VCE= -5.0VDC, f=100MHz)	f <sub>T</sub>	100	-	-	MHz
Output Capacitance (V <sub>CB</sub> = -10V, f=1.0MHz)	C <sub>obo</sub>	-	-	4.5	pF
Noise Figure (I <sub>C</sub> = -0.2mA, V <sub>C</sub> E= -5.0Vdc, Rs=2.0k $\Omega$ , f=1.0kHz, BW=200Hz) BC856, BC857, BC858 Series BC859, Series	NF		-	10 4.0	dB

### **Device Marking**

BC856A=3A; BC856B=3B; BC857A=3E; BC857B=3F; BC857C=3G BC858A=3J; BC858B=3K; BC858C=3L; BC859B=4B; BC859C=4C



#### BC857/BC858/BC859 Series

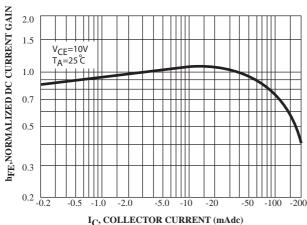
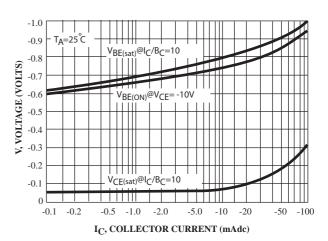


Figure 1. Normalized DC Current Gain



Firure2. "Saturation" And "On" Voltage

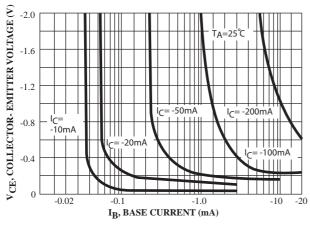


Figure 3. Collector Saturation Region

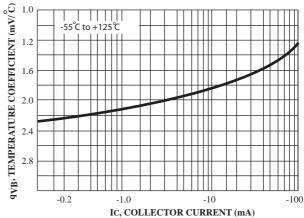


Figure 4. Base-Emitter Temperature Coefficient

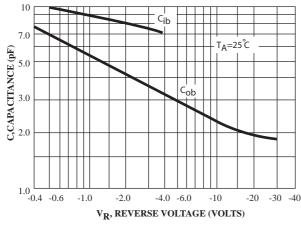


Figure 5. Capacitances

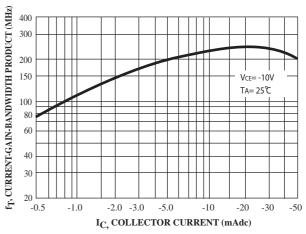


Figure 6. Current-Gain- Bandwidth Product



#### **BC856 Series**

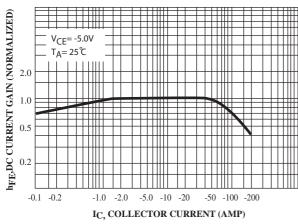


Figure 7. DC Current Gain

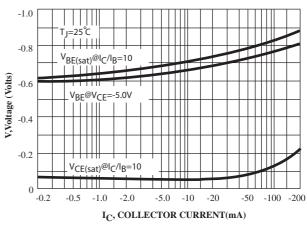


Figure 8. "ON" Voltage

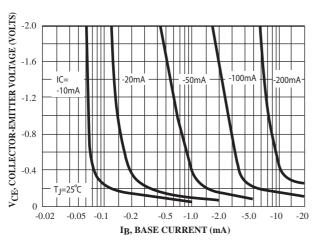


Figure 9. Collector Saturation Region

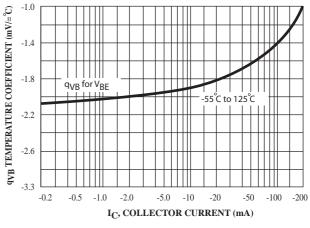


Figure 10. Base-Emitter Temperature Coefficient

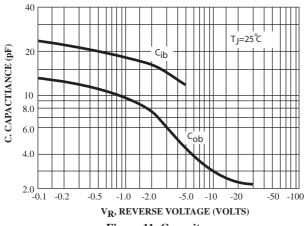


Figure 11. Capacitance

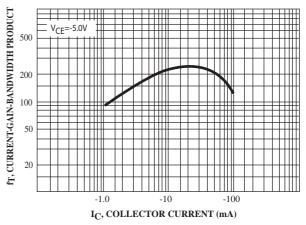


Figure 12. Current-Gain-Bandwidth Product